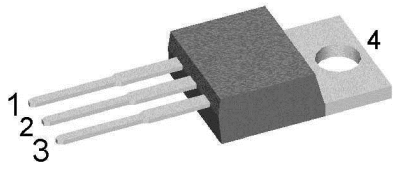
Schottky Diode

V_{RRM} = 200 V
I_{FAV} = 2x 15 A
V_F = 0.78 V

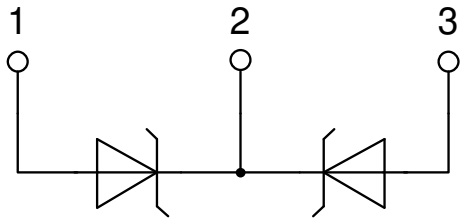
High Performance Schottky Diode
Low Loss and Soft Recovery
Common Cathode

Part number

DSA30C200PB



Backside: cathode



Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-220

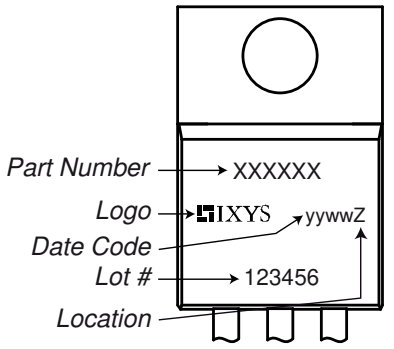
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Schottky

Symbol	Definition	Conditions		Ratings min.	typ.	max.	Unit
V_{RSM}	*max. non-repetitive reverse blocking voltage*		T_{VJ} = 25°C			200	V
V_{RRM}	*max. repetitive reverse blocking voltage*		T_{VJ} = 25°C			200	V
I_R	*reverse current, drain current*	V_R = 200 V	T_{VJ} = 25°C			250	µA
		V_R = 200 V	T_{VJ} = 125°C			2.5	mA
V_F	*forward voltage drop*	I_F = 15 A	T_{VJ} = 25°C			0.94	V
		I_F = 30 A				1.10	V
		I_F = 15 A	T_{VJ} = 125°C			0.78	V
		I_F = 30 A				0.95	V
I_{FAV}	*average forward current*	T_C = 155°C	T_{VJ} = 175°C			15	A
		rectangular d = 0.5					
V_{F0}	*threshold voltage* } *for power loss calculation only*		T_{VJ} = 175°C			0.53	V
r_F	*slope resistance* }					10.8	mΩ
R_{thJC}	*thermal resistance junction to case*					1.75	K/W
R_{thCH}	*thermal resistance case to heatsink*				0.50		K/W
P_{tot}	*total power dissipation*		T_C = 25°C			85	W
I_{FSM}	*max. forward surge current*	t = 10 ms; (50 Hz), sine; V_R = 0 V	T_{VJ} = 45°C			320	A
C_J	*junction capacitance*	V_R = 48 V f = 1 MHz	T_{VJ} = 25°C		47		pF

Package TO-220			Ratings			
Symbol	**Definition**	**Conditions**	**min.**	**typ.**	**max.**	**Unit**
I_{RMS}	*RMS current*	per terminal 1)			35	A
T_{VJ}	*virtual junction temperature*		-55		175	°C
T_{op}	*operation temperature*		-55		150	°C
T_{stg}	*storage temperature*		-55		150	°C
Weight				2		g
M_D	*mounting torque*		0.4		0.6	Nm
F_C	*mounting force with clip*		20		60	N

Product Marking



Part description

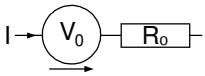
D = Diode
S = Schottky Diode
A = low VF
30 = Current Rating [A]
C = Common Cathode
200 = Reverse Voltage [V]
PB = TO-220AB (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA30C200PB	DSA30C200PB	Tube	50	507014

Similar Part	Package	Voltage class
DSA30C200IB	TO-262 (I2Pak) (3)	200
DSA30C200PC	TO-263AB (D2Pak) (2)	200

Equivalent Circuits for Simulation

** on die level* T_{VJ} = 175 °C



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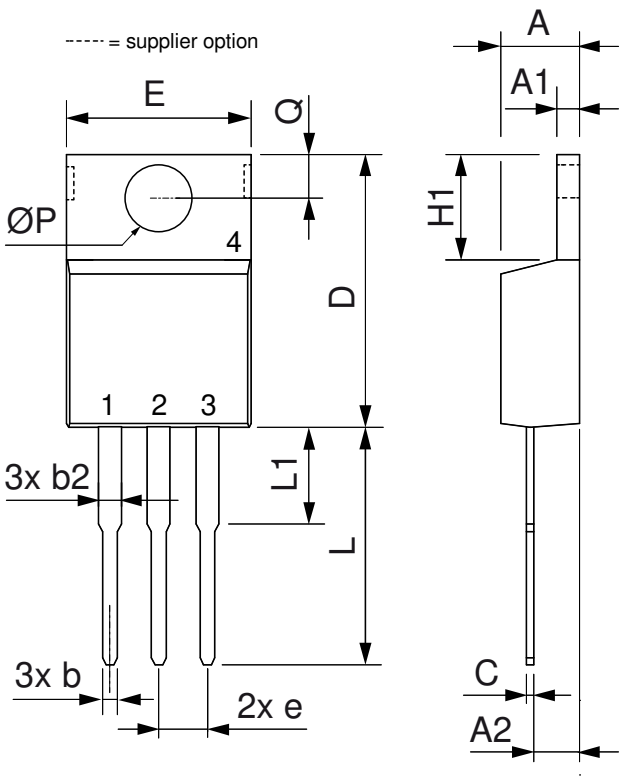
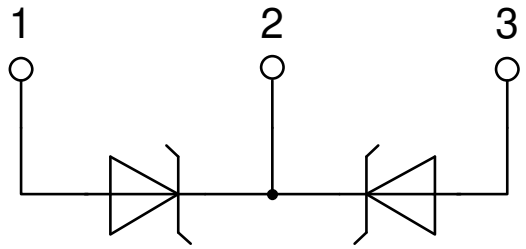
$V_{0\,max}$	*threshold voltage*	0.53	V
$R_{0\,max}$	*slope resistance **	7.6	mΩ

Outlines TO-220



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
C	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
e	2.54	BSC	0.100	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
ØP	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125



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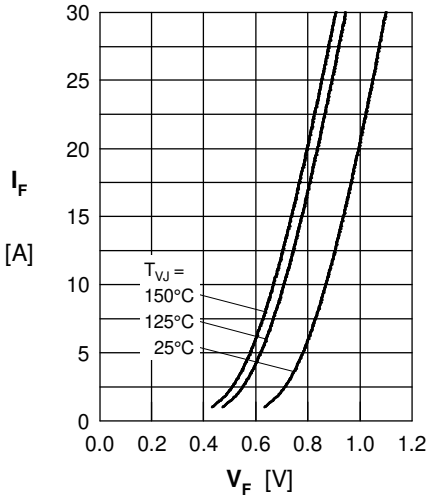

Fig. 1 Maximum forward voltage drop characteristics

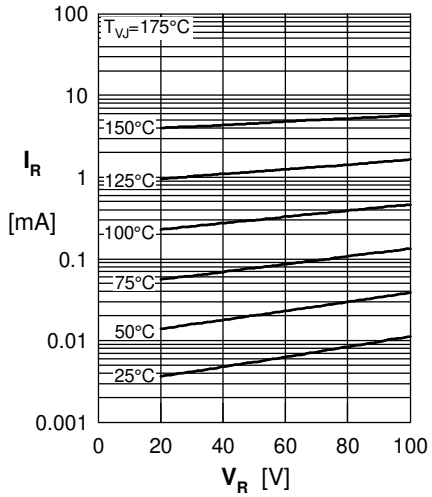

Fig. 2 Typ. reverse current I_R vs. reverse voltage V_R

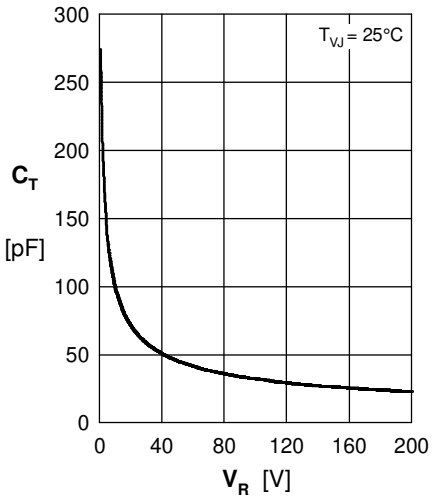

Fig. 3 Typ. junction capacitance C_T vs. reverse voltage V_R

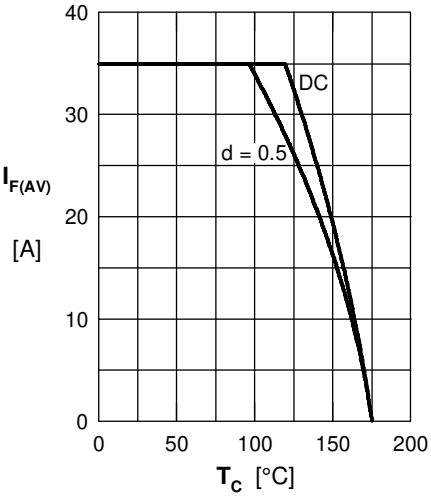

Fig. 4 Average forward current $I_{F(AV)}$ vs. case temperature T_C

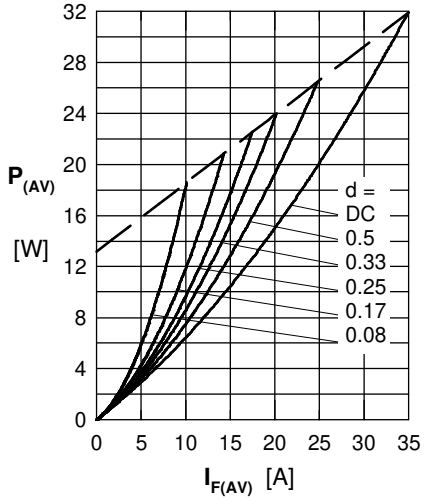

Fig. 5 Forward power loss characteristics

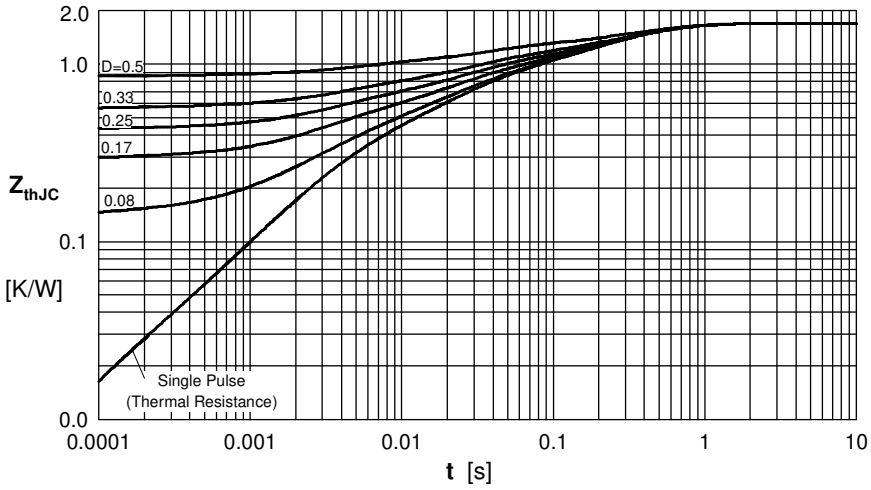

Fig. 6 Transient thermal impedance junction to case

Note: All curves are per diode